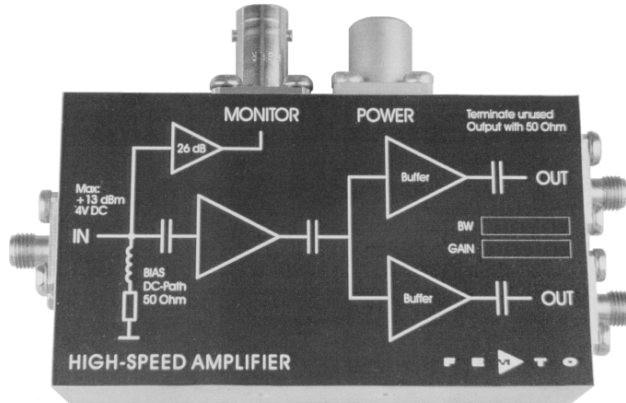




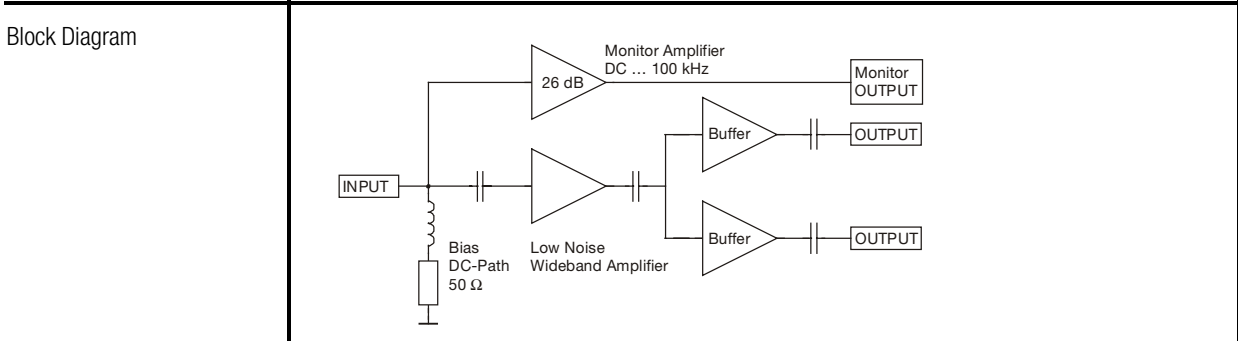
Datasheet **HSA-Y-2-40**

2 GHz High-Speed Amplifier



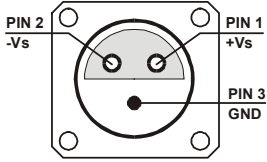
| | |
|----------|---|
| Features | <ul style="list-style-type: none"> • Bandwidth 10 kHz ... 1.9 GHz • Rise Time 185 ps • Gain 40 dB (5 kV/A) • Input VSWR 1 : 1.2 • Integrated Bias Circuit • Monitor Output • Two identical Signal Outputs |
|----------|---|

| | |
|--------------|---|
| Applications | <ul style="list-style-type: none"> • Preamplifier for ultra-fast Detectors (Microchannel-Plates, Photomultipliers, Avalanche-Photodiodes, PIN-Photodiodes etc.) • Oscilloscope and Transient-Recorder Preamplifier • Time-Resolved Pulse and Transient Measurements |
|--------------|---|



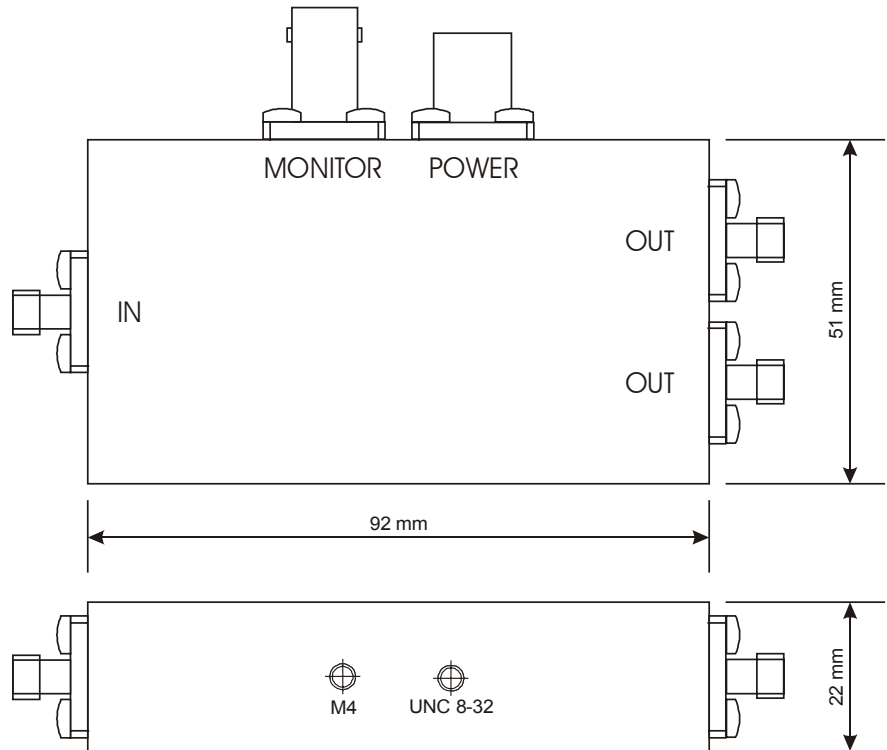
| | | | | | | | | | | | |
|------------------------|--|------------------------|--|------|--|--------------------|---|---------------|--------------------------------------|-------|---|
| Specifications | <table border="0"> <tr> <td>Test Conditions</td> <td>$V_s = \pm 15\text{ V}$, $T_a = 25^\circ\text{C}$, System Impedance = $50\ \Omega$</td> </tr> <tr> <td>Gain</td> <td>Gain: 40 dB (5 kV/A) Gain Accuracy: $\pm 1\text{ dB}$ Gain Flatness: $\pm 0.2\text{ dB}$</td> </tr> <tr> <td>Frequency Response</td> <td>Lower Cut-Off Frequency: 10 kHz Upper Cut-Off Frequency: 1.9 GHz</td> </tr> <tr> <td>Time Response</td> <td>Rise / Fall Time (10% - 90%): 185 ps</td> </tr> <tr> <td>Input</td> <td>DC Input Impedance: $50\ \Omega$ RF Input Impedance: $50\ \Omega$ $50\ \Omega$ Noise Figure: 4.9 dB (@ $f < 1\text{ GHz}$) Equivalent Input Voltage Noise: 650 pV/$\sqrt{\text{Hz}}$ (@ $f < 1\text{ GHz}$) Equivalent Input Current Noise: 13 pA/$\sqrt{\text{Hz}}$ (@ $f < 1\text{ GHz}$) Input VSWR: 1 : 1.2 (@ $f < 1.5\text{ GHz}$) Maximum Input VSWR: 1 : 1.45 (@ $f < 3\text{ GHz}$)</td> </tr> </table> | Test Conditions | $V_s = \pm 15\text{ V}$, $T_a = 25^\circ\text{C}$, System Impedance = $50\ \Omega$ | Gain | Gain: 40 dB (5 kV/A) Gain Accuracy: $\pm 1\text{ dB}$ Gain Flatness: $\pm 0.2\text{ dB}$ | Frequency Response | Lower Cut-Off Frequency: 10 kHz Upper Cut-Off Frequency: 1.9 GHz | Time Response | Rise / Fall Time (10% - 90%): 185 ps | Input | DC Input Impedance: $50\ \Omega$ RF Input Impedance: $50\ \Omega$ $50\ \Omega$ Noise Figure: 4.9 dB (@ $f < 1\text{ GHz}$) Equivalent Input Voltage Noise: 650 pV/ $\sqrt{\text{Hz}}$ (@ $f < 1\text{ GHz}$) Equivalent Input Current Noise: 13 pA/ $\sqrt{\text{Hz}}$ (@ $f < 1\text{ GHz}$) Input VSWR: 1 : 1.2 (@ $f < 1.5\text{ GHz}$) Maximum Input VSWR: 1 : 1.45 (@ $f < 3\text{ GHz}$) |
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2 GHz High-Speed Amplifier

| | |
|--------------------------|--|
| Output | Two identical Signal Outputs: Output Impedance 50 Ω Maximum Output VSWR 1 : 1.8 (@ f < 3 GHz) Output Power P _{1dB} + 12 dBm (@ f < 1 GHz) Output Peak-Peak Voltage 1.7 Vpp (@ f < 500 MHz, for linear Amplification) Isolation between Outputs 20 dB (@ f < 3 GHz) |
| Monitor Amplifier | Gain 26 dB (1 kV/A) Lower Cut-Off Frequency DC Upper Cut-Off Frequency 100 kHz Output Voltage ± 10 V (@ 10kΩ load) |
| Power Supply | Supply Voltage ± 15 V Supply Current + 185 / -10 mA |
| Case | Weight 180 gr. (0.41 lbs) Material AlMg4.5Mn, nickel-plated |
| Temperature Range | Storage Temperature - 40 ... + 100 °C Operating Ambient Temperature 0 ... + 60 °C Operating Case Temperature 40 °C (@ Ta = 25 °C) |
| Absolute Maximum Ratings | Power Supply Voltage ± 20 V DC and LF Input Voltage ± 4 V RF Input Power + 13 dBm |
| Connectors | Input SMA Signal Outputs SMA Monitor Output BNC Power Supply LEMO Series 1S, 3-pin fixed Socket Pin 1: + 15 V Pin 2: - 15 V Pin 3: GND |
| |  |

2 GHz High-Speed Amplifier

Dimensions



DZ01-0611-10

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